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Structure-Property Relationship in Layered BaMn₂Sb₂ and Ba₂Mn₃Sb₂O₂

Qiang Zhang^{1,2}, Zhenyu Diao¹, Huibo Cao², Ahmad Saleheen¹, Ramakanta Chapai¹, Dongliang Gong¹, Shane Stadler¹, R. Jin^{1*}

¹Department of Physics and Astronomy, Louisiana State University, Baton Rouge, LA 70803 USA

²Neutron Scattering Division, Oak Ridge National Laboratory, Oak Ridge, TN 37831, USA

Abstract

Layered transition-metal compounds have received great attention owing to their novel physical properties. Here, we present the structural, electronic, thermal, and magnetic properties of BaMn₂Sb₂ and Ba₂Mn₃Sb₂O₂ single crystals, both with the layered structure analogous to high-temperature Cu- and Fe-based superconductors. While the Mn moment in the MnSb₄ tetrahedral environment forms a long-range *G*-type antiferromagnetic (AFM) ordering in both BaMn₂Sb₂ ($T_{N1} \approx 443$ K) and Ba₂Mn₃Sb₂O₂ ($T_{N1} \approx 314$ K), a short-range AFM order is found in the intercalated MnO₂ layer at a much lower temperature ($T_{N2} \approx 60$ K) coexisting with long-range *G*-type order in MnSb₄ layer in Ba₂Mn₃Sb₂O₂. The directions of the ordered moments in these two magnetic sub-lattices of Ba₂Mn₃Sb₂O₂ are perpendicular to each other, even though the system is electrically conductive. The *G*-type AFM order in MnSb₄ layers in both compounds is distinct from the stripe-like order in Fe-based superconductors, but the in-plane magnetic structure in MnO₂ layers of Ba₂Mn₃Sb₂O₂ is found to be similar to that in the Cuprates. Our study reveals the significant and distinct roles of the CuO₂- and FeAs₄-type transition metal layers in the structure, novel magnetic and electronic properties.

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I. INTRODUCTION

The discovery of high-transition-temperature (high- T_c) superconductivity in CuO₂-based¹ and FeAs₄-based² layered materials has triggered extensive studies of layered transition-metal compounds involving similar crystal structures and building blocks, aimed at searching for possible new superconductors and underlying physics. Compounds with the general formula AMn₂Pn₂ (A = an alkaline earth metal; Pn = pnictogen)³⁻⁶ are isostructural to AFe₂As₂^{2,7}, a parent compound of the 122-type Fe-based superconductors. The fundamental building block is the MnPn₄ tetrahedron, which forms a layer by edge sharing as shown in Fig. 1(a). In contrast to the metallic behavior in the AFe₂As₂ family, Mn-based BaMn₂Pn₂ has the semiconducting or insulating ground state⁴⁻⁶. Furthermore, BaMn₂As₂ was reported to exhibit a *G*-type antiferromagnetic (AFM) order⁴, distinct from the stripe-like AFM order in the AFe₂As₂ series^{2,7}. In addition, the replacement of As by heavier Sb may influence the physical properties of a system. For example, the AFM ordering temperature of CeMnSbO is much lower than that of CeMnAsO¹⁰. On the other hand, LiFeSb is predicted to have higher T_c than LiFeAs^{8,9}.

Besides chemical element replacement, another way of designing new superconductors involves the inclusion of both the FeAs₄- and CuO₂- types building blocks. Compounds with the general formula $A_2Mn_3Pn_2O_2$ are built upon Mn(1)Pn₄ and Mn(2)O₂ building blocks (see Fig. 1(b)) ¹¹⁻¹⁵, the latter being similar to the CuO₂ layer in high- T_c cuprates. These mixed-layer compounds are particularly interesting since the two different types of Mn layers/ building blocks units segregate into specific crystallographic sites within the same compound in a chemically controlled manner and the incorporation of two different Mn layers may create novel properties. $A_2Mn_3Pn_2O_2$ can be viewed as the insertion of a Mn(2)O₂ layer in AMn₂Pn₂ separated by A. The structural similarity between AMn₂Pn₂ and $A_2Mn_3Pn_2O_2$ offers an excellent opportunity to study the structure-property relationship, especially the roles of the CuO_2 - and FeAs₄-type layers in their physical properties. In this article, we focus on the experimental investigation of the structural and physical properties of BaMn₂Sb₂ and Ba₂Mn₃Sb₂O₂ single crystals. The comparative studies allow us to identify the roles of the Mn(1)Sb₄ and Mn(2)O₂ layers in the physical properties of these compounds to shed light on their structure-property correlation.

II. EXPERIMENTAL DETAILS

Single crystals of BaMn₂Sb₂ and Ba₂Mn₃Sb₂O₂ were grown by the flux method using Sn as flux. For the growth of BaMn₂Sb₂, Ba rod (Alfa Aesar 99+%), Mn powder (Alfa Aesar, 99.95%), Sb powder (Alfa Aesar, 99.999%), and Sn powder (Alfa Aesar, 99.995%) were mixed in the ratio of 1 : 2 : 2 : 5, and placed in an alumina crucible. The crucible was then sealed in an evacuated quartz tube. The whole assembly was first sintered at 1180 °C for 15 h, and then slowly cooled down to 700 °C at a rate of 5 °C/h. The sealed quartz tube was taken out of the furnace, spun in a centrifuge, and finally quenched to room temperature. The same temperature profile and procedure were used to grow Ba₂Mn₃Sb₂O₂ single crystals successfully for the first time out of the mixture of BaO : Mn : Sb : Sn with the ratio of 2 : 3 : 2 : 5. In both growths, plate-like single crystals with surfaces over 5 mm × 5 mm were obtained, which are very malleable and easily bent.

The compositions of grown crystals were measured using the wavelength dispersive spectroscopy (WDS) technique. For targeted $BaMn_2Sb_2$, the average elemental ratio was found to be Ba : Mn : Sb = 1 : 1.94 : 2, which is consistent with 1 : 2 : 2 stoichiometry with slight Mn

deficiency. For targeted $Ba_2Mn_3Sb_2O_2$, WDS indicates that the average elemental ratio is Ba: Mn : Sb : O = 2: 2.85: 1.98: 1.89, with slight Mn and O deficiencies.

The crystal structures were identified using both power and single crystal x-ray diffraction (XRD) with Cu K α (λ = 1.5418 Å) radiation, and neutron diffraction. For crystallographic and magnetic structure determination, single crystal neutron diffraction measurements were performed at the HB-3A four-circle diffractometer in the High Flux Isotope Reactor (HFIR) at the Oak Ridge National Laboratory (ORNL). Neutrons of wavelength 1.003 Å were employed via a bent Si-331 monochromator without $\lambda/2$ contamination¹⁶ to investigate BaMn₂Sb₂. Neutrons of wavelength 1.546 Å (with high flux involving $\sim 1.4\% \lambda/2$ contamination) from the Si-220 monochromator¹⁶ were used for Ba₂Mn₃Sb₂O₂. For each measurement, a crystal sample was placed on an Al holder with aluminum foil in an evacuated sample space. A high temperature close cycle refrigerator (CCR) furnace was installed, so that the measurements can be performed between 6 K and 800 K. Electrical resistivity and thermopower were measured using the standard four-probe method. To improve the electrical contact between the sample surface and leads, a thin layer of Au was deposited prior to attaching leads. Measurements of electrical resistivity, thermopower, and specific heat were performed in a Physical Property Measurement System (PPMS, *Quantum Design*) between 2 K and 400 K. Magnetic susceptibility measurements were carried out in a Superconducting Quantum Interference Device (SQUID, Quantum Design) between 2 K and 700 K, where a sample space oven option was used for hightemperature (> 400 K) measurements.

III. RESULTS AND DISCUSSION

A. Crystalline structure

The XRD measurements on crushed BaMn₂Sb₂ and Ba₂Mn₃Sb₂O₂ crystals show that there are no impurity phases, except for a tiny amount of residual Sn flux (not shown). The Rietveld analyses on the single crystal neutron diffraction data confirm the tetragonal structure with the space group *I4/mmm* (No. 139) for both compounds¹⁷⁻¹⁸, as illustrated in Figs. 1(a) and 1(b), respectively. For both compounds, there is no evidence for any structural transitions down to 6 K. The refined lattice parameters, atomic positions, and reliability factors from our neutron data taken at 6 K are summarized in Table I. For BaMn₂Sb₂, the Mn(1)Sb₄ layer is similar to the FeAs layer formed with edge-shared tetrahedra. For Ba₂Mn₃Sb₂O₂, there are extra Mn(2)O₂ and Ba layers to separate Mn(1)Sb₄ tetrahedral layers, leading to a much larger lattice constant *c* (= 20.78 Å) than that of BaMn₂Sb₂ (= 14.28 Å). In contrast, the lattice constant *a* for Ba₂Mn₃Sb₂O₂ is slightly shorter than that for BaMn₂Sb₂.

B. Electrical resistivity and thermopower

The temperature (*T*) dependence of the in-plane resistivity (ρ_{ab}) of BaMn₂Sb₂ (circles) and Ba₂Mn₃Sb₂O₂ (squares) is shown in Fig. 2(a). For BaMn₂Sb₂, the resistivity increases with decreasing temperature in the entire temperature range measured, indicating a non-metallic behavior as reported previously ¹⁹. Below $T_x \approx 180$ K, the change of ρ_{ab} is slower than that at higher temperatures. We fit the electrical conductivity ($\sigma_{ab}=1/\rho_{ab}$) above T_x using the formula $\sigma_{ab} = \sigma_0 + Bexp(-\frac{\Delta}{2k_BT})$, where σ_0 and B are constants, k_B is the Boltzmann constant, and Δ is the energy gap. The fit yields $\sigma_0 = 0.021 \ \Omega^{-1}$ cm⁻¹, B = 4830 Ω^{-1} cm⁻¹, and $\Delta = 0.411$ eV. We thus infer that BaMn₂Sb₂ a semiconductor. Below T_x , $\rho_{ab}(T)$ can be described by $\rho_{ab} = -6.47(5) \ln T + 77.2(1) \ \Omega$ -cm. This crossover from activated to logarithmic temperature dependence is very similar to that of Ba₂Mn₂Sb₂O²⁹. The origin of the crossover in $Ba_2Mn_2Sb_2O$ was attributed to an AFM phase transition. For $BaMn_2Sb_2$, it does not seem to have a magnetic phase transition around T_x , even though the magnetic susceptibility shows an anomaly.

In contrast, the electric resistivity of Ba₂Mn₃Sb₂O₂ differs from that of BaMn₂Sb₂, which (1) roughly three orders of magnitude lower, and (2) exhibits opposite temperature dependence. Note that, upon cooling, ρ_{ab} initially decreases, followed by an anomalous increase below ${\approx}320$ K, and then decreases again below ≈ 260 K. The small upturn below $T_{\rm N1} \approx 320$ K should be related to an AFM ordering in the Mn(1)Sb₄ layer (see discussion below). The non-monotonic character of $\rho_{ab}(T)$ suggests two-channel electrical conduction: one is based on the Mn(1)Sb₄ tetrahedral layer and another on the $Mn(2)O_2$ layer. The latter is more metallic than the former, leading to the metallic ground state (the residual resistivity is $\approx 35 \text{ m}\Omega$ cm). The metallic behavior observed in Ba₂Mn₃Sb₂O₂ is truly surprising, as all known 2322-type compounds such as Sr₂Mn₃As₂O₂ are insulating¹⁵. The metallicity was only observed in Sr₂(Mn₂Cu)As₂O₂¹⁵, where Cu was considered to partially replace Mn in the MnAs₄ layer. Our results suggest that the metallic behavior in $Ba_2Mn_3Sb_2O_2$ is mainly driven by the presence of the MnO₂ layer. According to previous study, monolayer MnO₂ is non-metallic above ~60 K but metallic below ~60 K 20 . Such metal-insulator transition is absent in Ba₂Mn₃Sb₂O₂. There are two possible scenarios. One is that the $Mn(2)O_2$ layer in the $Ba_2Mn_3Sb_2O_2$ environment is intrinsically different from the free-standing monolayer, thus having different properties. This is further supported by the fact that the magnetic structure of the $Mn(2)O_2$ layer in $Ba_2Mn_3Sb_2O_2$ is different from that in bulk MnO2²¹. Another possibility is that the good conduction of the Mn(2)O₂ layer results from oxygen deficiency as reflected in the WDS measurements. However,

WDS also indicates Mn deficiency. How Mn and O deficiency influences the electrical transport requires further investigation.

Despite the stark difference in the electrical transport between the two compounds, we observe very similar features in thermopower. Figure 2(b) displays the temperature dependence of thermopower (*S*) measured by applying thermal current along the *ab* plane for BaMn₂Sb₂ (circles) and Ba₂Mn₃Sb₂O₂ (squares), both having similar magnitude and undergoing several sign changes in the temperature range measured. The sign change clearly indicates that, in both compounds, there are two types of carriers: hole dominant when S > 0, and electron dominant when S < 0. For BaMn₂Sb₂, the minimum *S* occurs near T_x . For Ba₂Mn₃Sb₂O₂, the sign change at $T_{N1} \approx 320$ K, and the peak $T_{N2} \approx 60$ K is likely associated with the magnetic transitions, as will be discussed below.

C. Magnetic susceptibility and specific heat

The temperature dependence of magnetic susceptibility $\chi = M/H$ of BaMn₂Sb₂, measured at 1000 Oe applied magnetic field along both the *ab* plane and *c* axis, is shown in Fig. 2(c). Upon cooling, χ_{ab} initially increases with decreasing temperature, revealing a kink around 440 K as shown in the inset of Fig. 2(c), consistent with the previous report¹⁹. Below $T_x \approx 180$ K, χ_{ab} increases much faster than at high temperatures. Correspondingly, χ_c has a minimum at the same temperature, above which χ_c increases with temperature. The anomaly in the susceptibility was also reported previously but at a much lower temperature ~50 K¹⁹.

To understand the nature of the anomaly occurring at T_x , we measured the temperature dependence of the heat capacity (C_p) for BaMn₂Sb₂, as shown in the inset of Fig. 2(b). There is no anomaly between 2 and 300 K, indicating the absence of a phase transition around T_x . At 300

K, the measured C_p is 127 J/mol-K, which is consistent with the classical Dulong Petit specific heat value given by C_p = 3nR ~ 125 J/mol-K (where n is the number of atoms per formula and R is the molar gas constant). The obtained specific heat is quite similar to that of BaMn₂As₂²² and BaMn₂Bi₂²³. At low temperatures, C_p(T) can be fitted by C_p/T = $\gamma + \beta T^2$, yielding $\gamma = 0.0064(1)$ J/K²mol and $\beta = 0.0011(1)$ J/K⁴mol. The small but nonzero Sommerfeld coefficient γ suggests finite density of states likely resulting from impurity contribution to the electronic states. Assuming the βT^2 term arises from the lattice, we can estimate the Debye temperature θ_D using the relationship $\Theta_D = (\frac{12\pi^4 Rn}{5\beta})^{1/3} T^2$, which gives $\theta_D = 207$ K. Note that BaMn₂Sb₂ is antiferromagnically ordered at low temperatures as shown below. Thus, the excitations of spin waves may also contribute to β^{24} .

Interestingly, the temperature dependence of the magnetic susceptibility of Ba₂Mn₃Sb₂O₂ is quite different from that of BaMn₂Sb₂. As shown in Fig. 2(d), both χ_{ab} and χ_c of Ba₂Mn₃Sb₂O₂ increase with decreasing temperature, with a kink near $T_{N1} \approx 314$ K. Below $T_{N2} \approx 60$ K, both χ_{ab} and χ_c decrease with temperature before Curie tail-type increase. These anomalies suggest that there are two possible magnetic transitions.

D. Magnetic structures determined by single-crystal neutron diffraction

To understand the complex physical properties observed in BaMn₂Sb₂ and Ba₂Mn₃Sb₂O₂, we carried out single-crystal neutron diffraction measurements. Figures 3(a) and 3(b) show the rocking curves of a nuclear (110) peak and a magnetic (101) peak of BaMn₂Sb₂ at different temperatures, respectively. The rocking curves are fitted by two Gaussian peaks that correspond to two single-crystal domains. Note that the intensity of the (110) peak, shown in Fig. 3(a), has weak temperature dependence between 6 and 680 K. In contrast, the (101) peak, displayed in Fig.

3(b), undergoes a rapid increase below 460 K. This indicates that there is a magnetic transition, and the (101) peak is not only a nuclear peak but a magnetic peak. We thus trace the temperature dependence of both the (110) and (101) peak intensities, which are plotted in Fig. 3(c). The sudden increase of the (101) peak intensity marks the magnetic transition at $T_N \approx 441$ K. It is worth noting that we did not observe the short-range magnetic order above T_N since the linewidth and integrated intensity of the (101) peak are almost unchanged below/above T_N . Note that there is neither the intensity anomaly in a few peaks such as (110) (see dash line in Fig. 3(c)), (101), (002), (310) and (008) nor an emergence of new magnetic peaks below T_x , precluding a magnetic origin for the anomaly in the resistivity.

The refinement was performed by the Rietveld method using the FullProf package ²⁵ on a set of nuclear and magnetic reflections at T = 6 K for BaMn₂Sb₂. All the magnetic reflections can be indexed on the crystal unit cell with a magnetic propagation vector $\mathbf{k} = (0, 0, 0)$. The SARAH representational analysis program ²⁶ is used to derive the symmetry allowed magnetic structures. The decomposition of the magnetic representation into the irreducible representations is $\Gamma_3 + \Gamma_6 + \Gamma_9 + \Gamma_{10}$, two of which are FM ($\Gamma_3 + \Gamma_9$) and two are AFM ($\Gamma_6 + \Gamma_{10}$). The symmetry allowed basis vectors are summarized in Table II. The neutron diffraction pattern is fitted well using the Γ_6 model of Mn(1) sublattice as shown in Fig. 4(a), indicating an AFM ordering below T_N . The determined magnetic structure is illustrated in Fig. 3(d), where Mn spins are antiparallel forming a nearest-neighbor (NN) antiferromagnetic alignment in both the *ab* plane as well as *c* axis, i.e., the *G*-type AFM order. The Mn moment is $3.83(3)\mu_B$ pointing along the *c* axis, consistent with the sharper decrease of χ_c than χ_{ab} below T_N . The magnetic structure and the ordered moment are similar to those in BaMn₂As₂ ⁴ and BaMn₂Bi₂ ²⁷. It is worth noting that the T_N of BaMn₂Sb₂ may be

attributed to the longer Mn-Sb distance of 2.753 Å as determined from our refinement, compared to the shorter Mn-As distance of 2.558(2) Å in BaMn₂As₂⁴, resulting in a weaker superexchange (SE) magnetic interaction *via* the SE pathway Mn-Sb-Mn^{10,28}. The ordered moment suggests Mn²⁺ in its high spin state with total spin = 5/2, similar to that in BaMn₂Bi₂²⁷ and BaMn₂As₂⁴. The reduced moment for the high-spin state of Mn²⁺ is common, likely resulting from the strong hybridization between Sb *p* and Mn *d* orbitals ^{10,29-30}. In addition, the slight Mn deficiency is also expected to reduce the actual moment.

To determine the magnetic structures of Ba₂Mn₃Sb₂O₂, two sets of data were collected at 100 K ($T_{N2} < T < T_{N1}$) and 6 K ($T < T_{N2}$), respectively. At 100 K, the magnetic peaks can be indexed in the unit cell, indicative of the propagation vector $\mathbf{k} = (0, 0, 0)$. Fig. 5(a) shows the (101) peak at indicated temperatures. Similar to what was observed in BaMn₂Sb₂, the intensity of (101) increases with decreasing temperature, while the (110) peak intensity remains almost unchanged (not shown here). This implies the same *G*-type AFM order as in BaMn₂Sb₂. The temperature dependence of the (101) peak shown in Fig. 5(d) identifies the clear magnetic transition at $T_{N1} \approx 314$ K, consistent with the kink observed in the resistivity (see Fig. 2(a)) and susceptibility (see Fig. 2(d)). Interestingly, new magnetic peaks appear with the propagation vector of $\mathbf{k} = (0.5, 0.5, 0)$ at 6 K. Fig. 5(b) shows the rocking curves for the magnetic peak (0.5 0.5 2) at 6 (black dots) and 100 K (red dots). The temperature dependence of the (0.5 0.5 0) magnetic peak shows another magnetic transition at $T_{N2} \approx 60$ K, corresponding to the anomaly in the susceptibility shown in Fig. 2(d). Symmetry-allowed magnetic structures with these two propagation vectors are summarized in Table II.

Through the refinement shown in Fig. 4(b), we obtain a *G*-type AFM order (Γ_6 model) for Mn(1) in the Mn(1)Sb₄ tetrahedral layer without moment on Mn(2) in the Mn(2)O₂ layer at

100 K, as illustrated in Fig. 5(e). It is worthwhile pointing out that single Γ_3 or Γ_9 with nonzero Mn(1) and Mn(2) moments failed to refine the neutron data well. The magnetic moment of Mn(1)also points along the c axis with $m_c = 3.447(6)\mu_B$ at 100 K. Such a G-type AFM order persists below $T_{\rm N2}$, and the ordered moment slightly increases upon the decrease of temperature with m_c = $3.617(7)\mu_B$ at 6 K (see the refinement in Fig. 4(c)). Similar to BaMn₂Sb₂, the G-type AFM order in the Mn(1) sublattice is formed by the SE magnetic interaction via the SE pathway Mn(1)-Sb-Mn(1). At 6 K, the refinement on several dozen of magnetic peaks with k = (0.5, 0.5, 0.5, 0.5)0) reveals an AFM order in Mn(2) of the Mn(2)O₂ layer, with the refinement goodness $R_{\rm f}$ -factor ≈ 8.5 and $\chi^2 \approx 4.1$ as displayed in Fig. 4(d). But the magnetic moment is along the diagonal [1 -1 0] direction, i.e., Γ_3 model. The NN Mn(2) spins are antiferromagnetically aligned in the *ab* plane but ferromagnetically aligned along the c axis, explaining why χ_c increases and χ_{ab} decreases below T_{N2} . The ordered moment is $\approx 3.56(4)\mu_B$ for Mn(2), comparable to that of Mn(1), indicating both Mn(1) and Mn(2) are in the high spin state (S = 5/2). The magnetic structure of Ba₂Mn₃Sb₂O₂ at $T < T_{N2}$ is illustrated in Fig. 5(f), with the magnetic unit cell 4 times of the crystal unit cell. The AFM order in Mn(2) sublattice may be formed by the SE interaction via 180° Mn-O-Mn exchange pathway.

The lower T_{N2} than T_{N1} indicates that the dominant intralayer NN magnetic interaction in Mn(2) sublattice is weaker than that in the Mn(1) sublattice. In addition, the resolution-limited linewidths of the rocking curves of the magnetic (101) peak in Fig. 5(a) suggest a long-range *G*-type AFM order in the Mn(1) sublattice. The linewidths of the magnetic peaks with $\mathbf{k} = (0.5, 0.5, 0)$ in the Mn(2) sublattice are much broader than the nuclear/magnetic (101) peak as shown in Fig. 5(b). While the H and K scans through the magnetic peaks are resolution limited, the L scan through magnetic peaks is much broader than the instrumental resolution, as illustrated in Fig.

5(c) for the (0.5 0.5 0) magnetic peak. This suggests a long-range order in the *ab* plane but a short-range order along the *c* direction. To determine the intrinsic correlation length along the L (or *c*) direction, we fit the experimental line-shape of the L scan to a Lorentz function $L(L) = \frac{c}{1+(L\times\xi)^2}$, convoluted with the instrumental resolution Gaussian function $G(L) = \exp(-L^2/(2(\frac{\sigma}{2\sqrt{\ln 4}})^2)))$. Here, $(\xi^*2\pi/c)^{-1}$ is the half width at half maximum of the Lorentzian function where ξ is defined as the magnetic correlation length^{31,32}, and σ is the full width at half maximum of the instrumental resolution Gaussian function with $\sigma \approx 0.0369$ (rlu), i.e., 0.0112 Å⁻¹. The deconvolution yields the magnetic correlation length along the *c* axis $\xi_c \approx 80$ Å, confirming a short-range AFM order along the *c* axis for the Mn(2) sublattice. The perpendicular arrangement between the Mn(1) and Mn(2) moments as well as their distinct orders in Mn(1) (long-range order) and Mn(2) (short-range order) sublattices at $T < T_{N2}$ indicate that there is probably weak coupling between them.

It is worthwhile comparing the magnetic structure of Ba₂Mn₃Sb₂O₂ with those of the isostructural Sr₂Mn₃Sb₂O₂¹¹ and Sr₂Mn₃As₂O₂^{11,12}. In Sr₂Mn₃Sb₂O₂, a different AFM order (Γ_5) with the magnetic moment along the diagonal [110] direction was reported in the Mn(2) sublattice, although the Mn(1) sublattice exhibits the same *G*-type AFM order with the moment along the perpendicular *c* axis ¹¹. In addition, the Mn(2) sublattice in Sr₂Mn₃Sb₂O₂ has long-range AFM ordering. The difference may result from the shorter inter-Mn(2)O₂-layer distance in Sr₂Mn₃Sb₂O₂ (10.079 Å) relative to that in Ba₂Mn₃Sb₂O₂ (10.389 Å). For Sr₂Mn₃As₂O₂, a short-range AFM order in the Mn(2) sublattice was reported ^{11,12}, with the same (*G*-type) AFM order in the Mn(1) sublattice. However, the magnetic structure of Mn(2) could not be determined because of the weak magnetic signal in a polycrystalline sample and single crystals are required for the determination of its magnetic structure.

Let us now compare the magnetic structures of Mn(1)Sb₄ and Mn(2)O₂ layers with those of the FeAs₄ layers in Fe-based superconductors and CuO₂ layers in cuprate superconductors, respectively. The *G*-type AFM order with moment along the *c* axis in Mn(1)Sb₄ layers in both BaMn₂Sb₂ and Ba₂Mn₃Sb₂O₂ is distinct from the stripe-like AFM order with the ordered moment along the *a* axis in the orthorhombic structure, i.e., the diagonal [1 1 0] direction in the tetragonal notation in Fe-based superconductors. Within the $J_1 - J_2 - J_c$ Heisenberg interaction model ³³, the in-plane checker-board-like AFM structure of the *G*-type order in BaMn₂Sb₂ and Ba₂Mn₃Sb₂O₂ suggests that the NN interaction J_1 is dominant, whereas the in-plane next-nearestneighbor interaction J_2 is very weak or negligible. Thus, we conclude that $J_2 \ll J_1/2$ in BaMn₂Sb₂ and Ba₂Mn₃Sb₂O₂ (Mn(1)). In contrast, $J_2 > J_1/2$ leads to a stripe-like AFM order in Fe-based superconductors³⁴. However, the in-plane magnetic structure in the Mn(2)O₂ layers of Ba₂Mn₃Sb₂O₂ is similar to that in the CuO₂ layers of La₂CuO_{4+x}³⁵ and La₂CuO_{4+x}³⁶. The in-plane NN spins are antiparallel with an ordered moment along the diagonal [1 1 0] direction of the tetragonal notation, corresponding to the *a* (or *b*) axis in the orthorhombic notation in cuprates^{35,36}. This comparison may provide a clue to suppress the magnetism in $Mn(1)Sb_4$ layer and also manipulate the magnetism in $Mn(2)O_2$ layer by chemical modification/control toward the possible superconductivity in $A_2Mn_3Pn_2O_2$ family of compounds. It also demonstrates the significant effect of the intercalated Ba and $Mn(2)O_2$ layers on the physical properties given the lattice symmetry is unchanged.

IV. CONCLUSION

In summary, we have investigated the structural, magnetic, and electrical and thermal transport properties of BaMn₂Sb₂ and Ba₂Mn₃Sb₂O₂. BaMn₂Sb₂ is found to be a semiconductor with a G-type AFM order below $T_N \approx 443$ K. Interestingly, the addition of Ba and Mn(2)O₂ layers into BaMn₂Sb₂ result in a variety of rich physical properties in Ba₂Mn₃Sb₂O₂. Two magnetic transitions are observed in $Ba_2Mn_3Sb_2O_2$: (1) a long-range G-type AFM order with moment along the c axis for Mn(1) in Mn(1)Sb₄ layers below $T_{N1} \approx 314$ K, and (2) a coexistence of the short-range AFM order in the $Mn(2)O_2$ layers with long-range G-type order in $MnSb_4$ layer below $T_{\rm N2} \approx 60$ K with moment along the diagonal direction in the *ab* plane. The perpendicular arrangement of two sets of magnetic moments may be caused by magnetic anisotropy or interaction in two sublattices, which requires further investigations. The metallic behavior observed in Ba₂Mn₃Sb₂O₂ may also be due to the Mn(2)O₂ layers, while the Mn(1)Sb₄ layers are non-metallic as seen in BaMn₂Sb₂. Remarkably, the G-type AFM order in Mn(1)Sb₄ layers in both compounds is distinct from the stripe-like order in Fe-based superconductors, and strikingly, the in-plane magnetic structure in the Mn(2) sublattice is similar to that of cuprates, which may provide a clue to suppress the magnetism in $Mn(1)Sb_4$ layer and simultaneously manipulate the

magnetism in $Mn(2)O_2$ layer by chemical modification/control toward the possible superconductivity in $A_2Mn_3Pn_2O_2$ family of compounds. Our study reveals the distinct roles of the CuO₂- and FeAs₄-type transition-metal layers in the novel physical properties and indicates that controlling the building blocks unit in the layered structure may be an effective way to discover and manipulate the novel physical properties.

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Compound	atom	Wyckoff site	х	у	Z	lattice constants	$R_{\rm f}$ -factor	χ^2
BaMn ₂ Sb ₂	Ba	2a	0	0	0	<i>a</i> = <i>b</i> =4.39(1)	4.9	1.25
	Mn	4d	0	0.5	0.25	<i>c</i> =14.28(5)		
	Sb	4e	0	0.25	0.366(3)			
$Ba_2Mn_3Sb_2O_2$	Ва	4e	0	0	0.417 (2)	<i>a</i> = <i>b</i> =4.367	2.23	1.6
	Mn(1)	4d	0	0.5	0.25	<i>c</i> =20.779		
	Mn(2)	2a	0	0	0			
	Sb	4e	0	0	0.168(3)			
	0	4c	0	0.5	0			

Table I. Crystal structures of $BaMn_2Sb_2$ and $Ba_2Mn_3Sb_2O_2$ with the space group *I4/mmm* (no. 139) at 6 K determined by single crystal neutron scattering at HB-3A.

Table II The symmetry-allowed basis vectors $[m_x m_y m_z]$ of the space group I4/*mmm* (no. 139) for Mn(1) sublattices with $\mathbf{k} = (0, 0, 0)$ in BaMn₂Sb₂ and for both Mn(1) and Mn(2) sublattices in Ba₂Mn₃Sb₂O₂, and for Mn(2) sublattice with $\mathbf{k} = (0.5, 0.5, 0)$ in Ba₂Mn₃Sb₂O₂. Mn(1)₁: (0 0.5 0.25), Mn(1)₂: (0, 0.5, 0.75), and Mn(2):(0, 0, 0).

k	atom	Γ_3	Γ_6	Г9	Γ_{10}	
(0, 0, 0)	Mn(1) ₁	$[0 \ 0 \ m_z]$	$[0\ 0\ m_z]$	[m _x -m _y 0]	[-m _x m _y 0]	
	Mn(1) ₂	$[0\ 0\ m_z]$	[0 0 -m _z]	$[m_x \operatorname{-} m_y 0]$	$[m_x - m_y 0]$	
	Mn(2)	$[0 \ 0 \ 2m_z]$		$[2m_x - 2m_y 0]$		
k	atom	Γ_3	Γ ₅	Γ_7		
(0.5, 0.5, 0)	Mn(2)	$[m_x - m_y 0]$	$[m_xm_y0]$	$[0 \ 0 \ m_z]$		

Figures and captions:



Figure 1. Crystal structure of $BaMn_2Sb_2$ (a) and $Ba_2Mn_3Sb_2O_2$ (b) using the best-fit parameters listed in Table I.



Figure 2. (a) Temperature dependence of the in-plane electrical resistivity, ρ_{ab} , for BaMn₂Sb₂ (circles) and Ba₂Mn₃Sb₂O₂ (squares); (b) Temperature dependence of Seebeck coefficient (*S*) of BaMn₂Sb₂ and Ba₂Mn₃Sb₂O₂. The inset shows the specific heat (C_p) as a function of temperature for BaMn₂Sb₂. (c) Temperature dependence of in-plane (χ_{ab}) (circles) and out-of-plane (χ_c) (squares) magnetic susceptibilities measured in a field of 1000 Oe for BaMn₂Sb₂. Inset: χ_{ab} between 300 and 700 K showing anomaly at $T_N \approx 441$ K; (d) Temperature dependence of χ_{ab} (circles) and χ_c (squares) for Ba₂Mn₃Sb₂O₂.



Figure 3. Neutron results on BaMn₂Sb₂: (a-b) Rocking curve scans at indicated temperatures for nuclear (110) peak (a) and magnetic (101) peak (b). The solid lines are fits using two Gaussian functions; (c) Temperature dependence of the integrated intensity of the (110) and (101) peaks obtained by the fits to the Gaussian function. The red dash line is the guide to eye; (d) Magnetic structure below $T_{\rm N1}$.



Figure 4. Comparison of the observed and calculated squared structure factors from our neutron diffraction data taken (a) at 6 K for BaMn₂Sb₂ with $\mathbf{k} = (0,0,0)$, (b) at 100 K for Ba₂Mn₃Sb₂O₂ with $\mathbf{k} = (0,0,0)$, (c) at 6 K for Ba₂Mn₃Sb₂O₂ with $\mathbf{k} = (0,0,0)$, and (d) at 6 K for Ba₂Mn₃Sb₂O₂ with $\mathbf{k} = (0.5,0.5,0)$. The magnetic representation analysis used for calculations can be found in the main text.



Figure 5. Neutron results on Ba₂Mn₃Sb₂O₂: (a-b) Temperature dependence of the intensity for the nuclear/magnetic (101) peak (a), and the magnetic (0.5 0.5 2) peak (b). The solid lines are the fits to data using one Gaussian function. The weak peak at 100 K results from the $\lambda/2$ contamination. (c) L scan through the magnetic (0.5 0.5 0) peak at 6 K. The solid line is the fit to data using the Lorentz function convoluted with the instrumental resolution Gaussian function (dashed line). (d) Temperature dependence of the (101) and (0.5 0.5 0) peak intensities. T_{N1} and T_{N2} are indicated. (e-f) Magnetic structures in $T_{N2} < T < T_{N1}$ (e) and $T < T_{N2}$